

II. Schottky Rectifier

BAT54WS

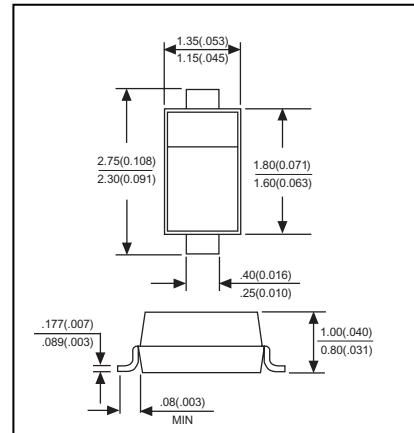
SOD-323

FEATURES

- Low turn-on voltage
- Fast switching
- Ultra-small surface mount package
- PN junction guard ring for transient and ESD protection

APPLICATIONS

- Schottky barrier detector and switching diodes



ORDERING INFORMATION

Type No.	Marking	Package Code
BAT54WS	L9	SOD-323

MAXIMUM RATING @ $T_a=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Limits	Unit
Peak Repetitive reverse voltage	V_{RRM}		
Working peak reverse voltage	V_{RWM}	30	V
DC reverse voltage	V_R		
RMS Reverse Voltage	$V_{R(RMS)}$	21	V
Average Rectified Output Current	I_O	100	mA
Repetitive peak Forward Current	I_{FRM}	300	mA
Forward Surge Current @ $t<1.0\text{s}$	I_{FSM}	600	mA
Power Dissipation	P_d	200	mW
Thermal resistance, junction to ambient air	$R_{\theta jA}$	625	°C/W
Junction temperature	T_j	125	°C
Storage temperature range	T_{stg}	-65 to +125	°C

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ELECTRICAL CHARACTERISTICS @ $T_A=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Reverse Breakdown Voltage	$V_{(\text{BR})R}$	$I_R=100\mu\text{A}$	30			V
Forward voltage	V_{F1}	$I_F=0.1\text{mA}$			240	mV
	V_{F2}	$I_F=1.0\text{mA}$			320	mV
	V_{F3}	$I_F=10\text{mA}$			400	mV
	V_{F4}	$I_F=30\text{mA}$			500	mV
	V_{F5}	$I_F=100\text{mA}$			1000	mV
Reverse leakage current	I_R	$V_R=25\text{V}$			2.0	μA
Reverse recovery time	t_{rr}	$I_F=10\text{mA}, I_R=10\text{mA}$ to 1mA $R_L=100\Omega$			5.0	ns
Junction capacitance	C_J	$V_R=1.0\text{V}, f=1.0\text{MHz}$			10	pF

TYPICAL CHARACTERISTICS @ $T_A=25^\circ\text{C}$ unless otherwise specified

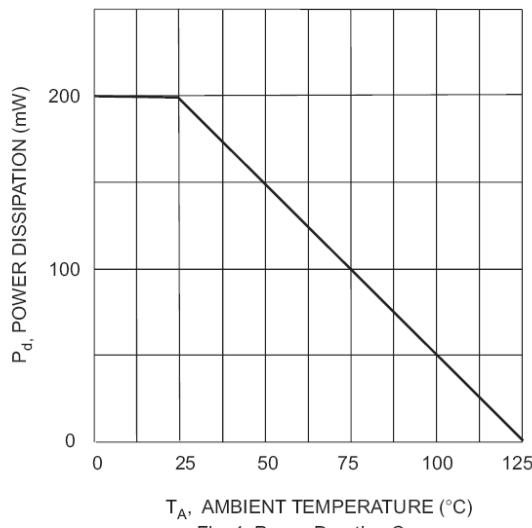


Fig. 1 Power Derating Curve

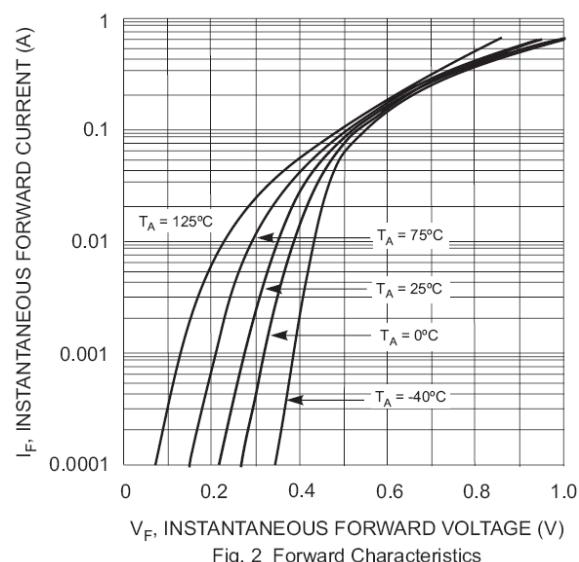


Fig. 2 Forward Characteristics

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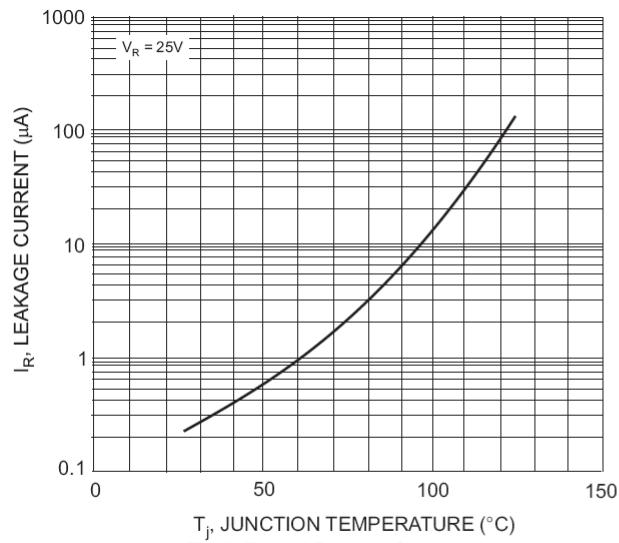


Fig. 3, Typical Reverse Characteristics

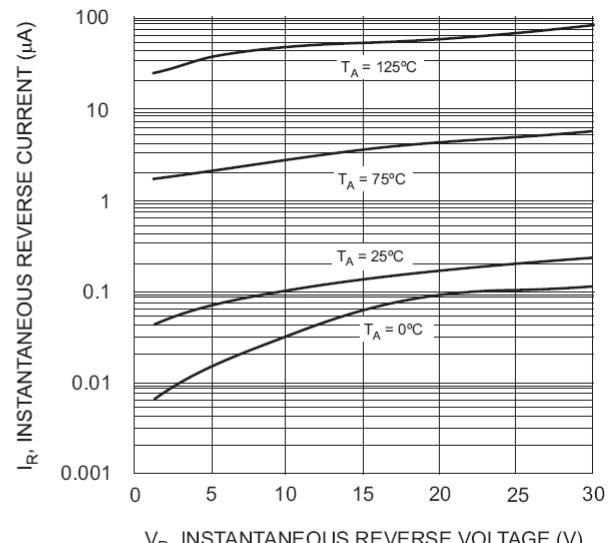


Fig. 4 Typical Reverse Characteristics

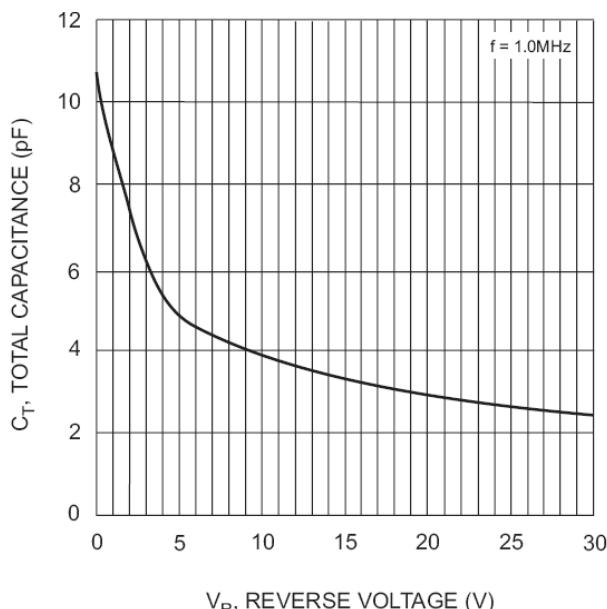


Fig. 5 Typical Capacitance vs. Reverse Voltage